<u>TOSHIBA</u>

Note: xxxFW (JEDEC SOP) is not available in

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC273AP,TC74HC273AF,TC74HC273AFW

Octal D-Type Flip Flop with Clear

The TC74HC273A is a high speed CMOS OCTAL D-TYPE FLIP FLOP fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overrightarrow{\text{CLR}}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 67 \text{ MHz}$ (typ.) at VCC = 5 V
- Low power dissipation: $I_{CC} = 4 \mu A (max)$ at $Ta = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 74LS273

Pin Assignment

CLR	1		\sim	20	V_{cc}
Q1	2			20 19 18 17 16 15 14 13 13 12 11	Q8
D1	3	q	1	1 18	D8
D2	4	q	1	1 17	D7
Q2	5	q		1 16	Q7
Q3	6	d	ļ	1 15	Q6
D3	7	d	1	14	D6
D4	8	d	t	1 13	D5
Q4	9	q		12	Q5
GND	10	٩] 11	СК
		(TOP	VIEW)	

Japan. TC74HC273AP DIP20-P-300-2.54A TC74HC273AF RANARAR SOP20-P-300-1.27A URRERERE SOP20-P-300-1.27 TC74HC273AFW SOL20-P-300-1.27 Weight DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.)

TOSHIBA

IEC Logic Symbol

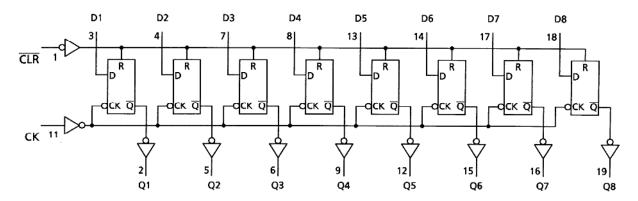
CLR (1) CK (11)	R > C1		
D1 (3) D2 (4) D3 (7) D4 (8) D4 (13) D5 (14) D6 (17) D7 (17)	10		(2) Q1 (5) Q2 (6) Q3 (9) Q4 (12) Q5 (15) Q6 (16) Q7
D8 (18)		-	(19) Q8

Truth Table

	Inputs		Output	Function
CLR	D	СК	Q	Tunction
L	Х	Х	L	Clear
Н	L		L	_
н	Н		Н	_
Н	Х		Qn	No change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I _{IK}	±20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of $Ta = -40 \sim 65^{\circ}$ C. From Ta = 65 to 85° C a derating factor of -10 mW/° C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		$0 \sim 1000 (V_{CC} = 2.0 V)$	
Input rise and fall time	t _r , t _f	$0{\sim}500 \ (V_{CC} = 4.5 \ V)$	ns
		$0{\sim}400 \ (V_{CC} = 6.0 \ V)$	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

			Test Condition		-	Ta = 25°0	2	Ta = -40~85°C		
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
				2.0	1.50		_	1.50	_	
High-level input voltage	VIH		_	4.5	3.15	_		3.15	—	V
				6.0	4.20	—	—	4.20	_	
				2.0	—	—	0.50	_	0.50	
Low-level input voltage	V _{IL}		—	4.5	—	—	1.35		1.35	V
Ũ				6.0	—	—	1.80		1.80	
		V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
	V _{OH}		$I_{OH} = -20 \ \mu A$	4.5	4.4	4.5	_	4.4	—	
High-level output voltage				6.0	5.9	6.0		5.9	—	V
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80		5.63	—	
				2.0	_	0.0	0.1	-	0.1	
		V _{IN}	$I_{OL}=20~\mu A$	4.5	_	0.0	0.1		0.1	
Low-level output voltage	V _{OL}	= V _{IH} or		6.0	_	0.0	0.1	_	0.1	V
		VIL	$I_{OL} = 4 \text{ mA}$	4.5	_	0.17	0.26		0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	$V_{IN} = V_C$	$V_{IN} = V_{CC}$ or GND		_	_	±0.1	_	±1.0	μA
Quiescent supply current	ICC	$V_{IN} = V_C$	_C or GND	6.0	_	_	4.0	_	40.0	μA

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 ~85°C	Unit	
			$V_{CC}(V)$	Тур.	Limit	Limit		
Minimum pulse width	t		2.0	_	75	95		
(CK)	tw (L)	—	4.5	_	15	19	ns	
(CK)	tw (H)		6.0	_	13	16		
Minimum pulse width			2.0	_	75	95		
(CLR)	t _{W (L)}	—	4.5	_	15	19	ns	
			6.0		13	16		
			2.0		75	95		
Minimum set-up time	ts	—	4.5	_	15	19	ns	
			6.0	_	13	16		
			2.0	_	0	0		
Minimum hold time	t _h	—	4.5	_	0	0	ns	
			6.0	_	0	0		
Minimum removal time			2.0	_	50	65		
	t _{rem}	—	4.5	_	10	13	ns	
(CLR)			6.0	_	9	11		
			2.0		6	5		
Clock frequency	f	—	4.5	—	30	24	MHz	
			6.0		35	28		

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}C$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	tтlн tтнl	_	_	4	8	ns
Propagation delay time (CK-Q)	t _{pLH} t _{pHL}	_		15	25	ns
Propagation delay time (CLR -Q)	t _{pLH} t _{pHL}	_		16	27	ns
Maximum clock frequency	f _{max}	—	40	67	_	MHz

AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

		Test Condition		-	Ta = 25°0)	Ta = -4	L La la	
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
	tтLн		2.0	_	25	75		95	
Output transition time		—	4.5	—	7	15		19	ns
	t THL		6.0	_	6	13		16	
Propagation delay	+		2.0		54	145	_	180	
time	t _{pLH}	—	4.5	—	18	29		36	ns
(CK-Q)	t _{pHL}		6.0	—	15	25		31	
Propagation delay	+		2.0	_	60	160	_	200	
time	t _{pLH}	—	4.5	_	20	32	_	40	ns
(<u>CLR</u> -Q)	t _{pHL}		6.0	_	17	27	_	34	
			2.0	6	18	_	5	_	
Maximum clock frequency	f _{max}	—	4.5	30	56	—	24	—	MHz
			6.0	35	66	—	28	—	
Input capacitance	C _{IN}	_		_	5	10		10	pF
Power dissipation capacitance	C _{PD} (Note)	_		_	43	_		_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per flip flop)

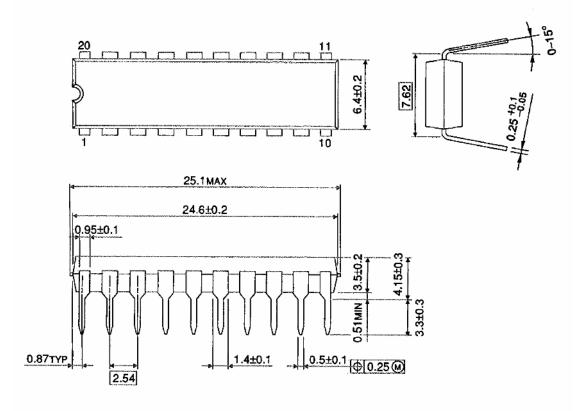
And the total C_{PD} when n pcs. of flip flop operate can be gained by the following equation:

 C_{PD} (total) = 32 + 11 · n

Package Dimensions

DIP20-P-300-2.54A

Unit : mm

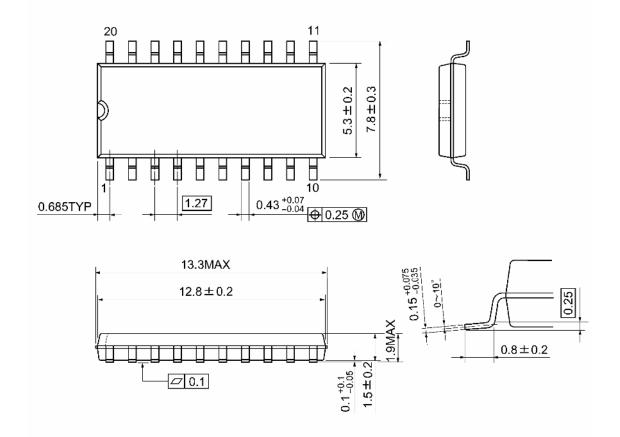


Weight: 1.30 g (typ.)

Package Dimensions

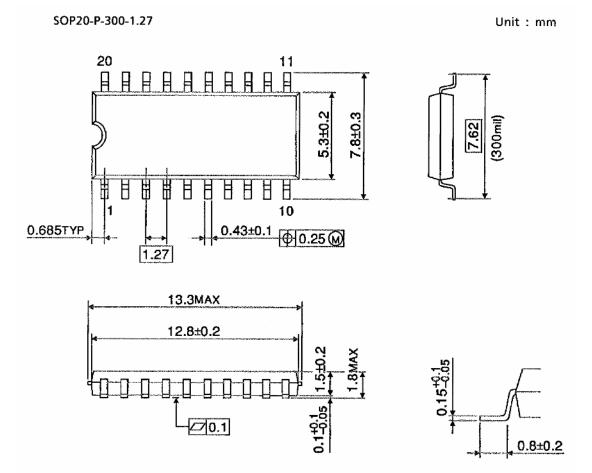
SOP20-P-300-1.27A

Unit: mm



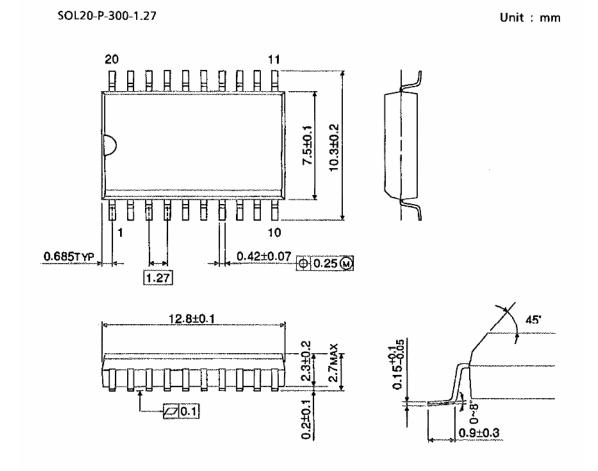
Weight: 0.22 g (typ.)

Package Dimensions



Weight: 0.22 g (typ.)

Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Note: Lead (Pb)-Free Packages DIP20-P-300-2.54A SOP20-P-300-1.27A

RESTRICTIONS ON PRODUCT USE

Handbook" etc. 021023 A

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